

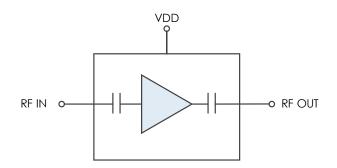
Description

AM1113 is a wideband, cascadable amplifier servicing the 2 to 18 GHz frequency range. The device exhibits low gain at the lower frequencies ascending to moderate gain at the higher frequencies. The increasing gain across frequency makes the AM1113 an ideal solution to equalize gain/insertion loss across an RF system. Packaged in a 3mm QFN with internal 50Ω matching and drawing less than 200mW of power, the AM1113 is suited for low SWaP applications.

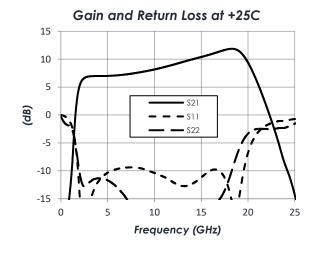
Features

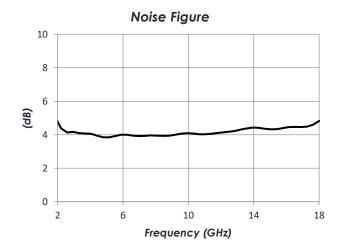
- 7 dB Gain Slope
- 5 dB Gain at 2 GHz
- 12 dB Gain at 18 GHz
- 4 dB Noise Figure
- +27 dBm OIP3
- +17 dBm P1dB
- +3.3V Operation
- 198 mW Power Consumption
- 3mm QFN
- -40C to +85C Operation

Functional Diagram



Characteristic Performance





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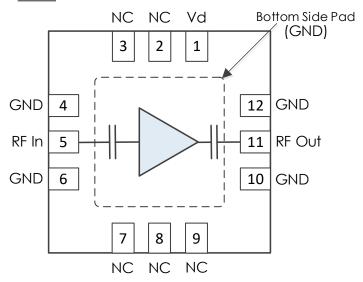
Revision History

| Date | Revision Number | Notes |
|-----------------|------------------------|-----------------|
| January 4, 2022 | 1 | Initial Release |



Pin Layout and Definitions

Note: All Un-Labeled Pins are NC or Ground



| Pin Number | Pin Name | Pin Function | |
|------------|----------|----------------------------------|--|
| 1 | Vd | DC Power Input | |
| 2-3 | NC | Not Connected | |
| 4 | GND | Ground - Common | |
| 5 | RF In | RF Input – 50 Ohms – DC Blocked | |
| 6 | GND | Ground – Common | |
| 7-9 | NC | Not Connected | |
| 10 | GND | Ground - Common | |
| 11 | RF Out | RF Output – 50 Ohms – DC Blocked | |
| 12 | GND | Ground - Common | |

Note: NC pins may be grounded or left open



Specifications

Absolute Maximum Ratings

| | Minimum | Maximum |
|---------------------------|---------|---------|
| Supply Voltage | -0.3 V | +3.5 V |
| RF Input Power | | +20 dBm |
| Storage Temperature Range | -55 C | +150 C |

Note: Any device operation beyond the Absolute Maximum Ratings may result in permanent damage to the device. The values listed in this table are extremes and do not imply functional operation of the device at these or any other conditions beyond what is listed under Recommended Operating Conditions. Any part subjected to conditions outside of what is recommended for an extended amount of time may suffer from reliability concerns.

Handling Information

| | Minimum | Maximum |
|---|---------|---------|
| Storage Temperature Range (Recommended) | -50 C | +125 C |
| Moisture Sensitivity Level | MSL 3 | |



Atlanta Micro products are electrostatic sensitive. Follow safe handling practices to avoid damage

Recommended Operating Conditions

| | Minimum | Typical | Maximum |
|----------------------------|---------|---------|---------|
| Supply Voltage | | +3.3 V | |
| Operating Case Temperature | -40 C | | +85 C |

Thermal Information

| Junction to Case Thermal Resistance (θ _{JC}) | 279 C/W |
|--|---------|
| Nominal Junction Temperature at +85C Ambient | +140 C |
| Channel Temperature to Maintain 1 Million Hour MTTF | +175 C |



DC Electrical Characteristics

(T = 25 °C unless otherwise specified)

| Parameter | Testing Conditions | Minimum | Typical | Maximum |
|-------------------|--------------------|---------|---------|---------|
| DC Supply Voltage | | | +3.3 V | |
| DC Supply Current | VDD = +3.3V | | 60 mA | |
| Power Dissipated | VDD = +3.3V | | 198 mW | |

RF Performance

(T = 25 °C unless otherwise specified)

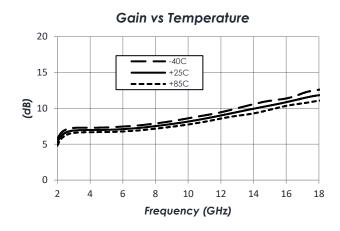
| Parameter | Testing Conditions | Minimum | Typical | Maximum |
|-----------------|---------------------------|---------|----------|---------|
| Frequency Range | | 2 GHz | | 18 GHz |
| Gain | f = 2 GHz | | 5 dB | |
| | f = 10 GHz | | 8 dB | |
| | f = 18 GHz | | 12 dB | |
| Return Loss | f = 2 GHz | | 12 dB | |
| | f = 10 GHz | | 13 dB | |
| | f = 18 GHz | | 12 dB | |
| Output IP3 | f = 10 GHz | | 28.5 dBm | |
| Output P1dB | f = 10 GHz | | 16 dBm | |
| Noise Figure | f = 10 GHz | | 4 dB | |

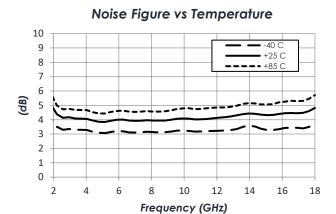
^{*}Note: OIP3 measured with 10MHz tone spacing

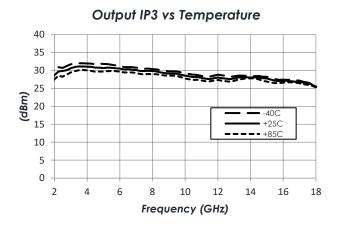


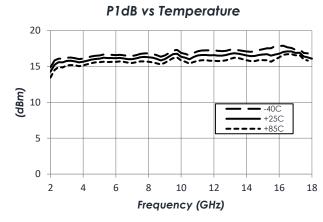
Typical Performance

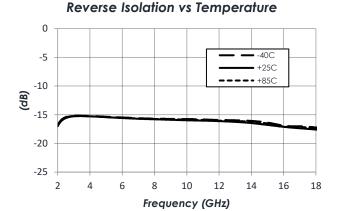
(VDD = +3.3V, T = 25°C unless otherwise specified)







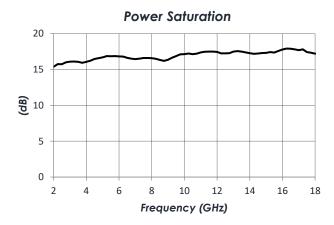


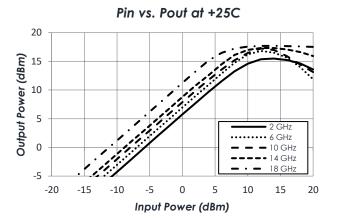




Typical Performance Continued

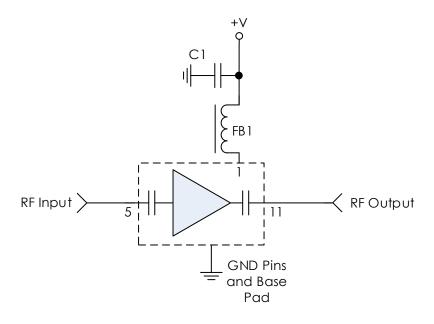
(VDD = +3.3V, T = 25°C unless otherwise specified)







Typical Application



Note: NC pins may be grounded or left open

Recommended Component List (or equivalent):

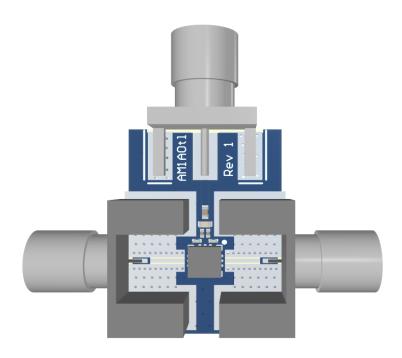
| Part | Value | Part Number | Manufacturer |
|------|--------|-------------------|--------------|
| C1 | 0.1 μF | GRM155R71C104KA88 | Murata |
| FB1 | - | MMZ1005A222E | TDK |

Notes:

- 1. FB1 and C1 are required for proper operation of the AM1113.
 - a. AM1113 <u>must</u> see a large-valued inductor or ferrite bead at pin 1 before a shunt capacitor is to be placed for power line filtering.
 - b. If a capacitor is placed at pin 1 before FB1, AM1113 will not operate as shown in Typical Performance section.



Evaluation PC Board



Note: Not all components shown may be installed.

Related Parts

| AM1070 | DC | to | 18 GHz | Broadband Gain Block |
|--------|-------|----|----------|----------------------------|
| AM1071 | DC | to | 18 GHz | Broadband Gain Block |
| AM1100 | 2 GHz | to | 16.5 GHz | Low Noise Amplifier |
| AM1101 | 2 GHz | to | 26.5 GHz | Bypassable Amplifier |
| AM1102 | DC | to | 22 GHz | Low Noise Amplifier |
| AM1110 | DC | to | 18 GHz | Slope Correcting Amplifier |
| AM1114 | 2 GHz | to | 18 GHz | Slope Correcting Amplifier |



Component Compliance Information

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| Substance List | Allowable Maximum Concentration |
|---------------------------------------|---------------------------------|
| Lead (Pb) | <1000 PPM (0.1% by weight) |
| Mercury (Hg) | <1000 PPM (0.1% by weight) |
| Cadmium (Cd) | <75 PPM (0.0075% by weight) |
| Hexavalent Chromium (CrVI) | <1000 PPM (0.1% by weight) |
| Polybrominated Biphenyls (PBB) | <1000 PPM (0.1% by weight) |
| Polybrominated Diphenyl ethers (PBDE) | <1000 PPM (0.1% by weight) |
| Decabromodiphenyl Deca BDE | <1000 PPM (0.1% by weight) |
| Bis (2-ethylheyl) Phthalate (DEHP) | <1000 PPM (0.1% by weight) |
| Butyl Benzyl Phthalate (BBP) | <1000 PPM (0.1% by weight) |
| Dibutyl Phthalate (DBP) | <1000 PPM (0.1% by weight) |
| Diisobutyl Phthalate (DIBP) | <1000 PPM (0.1% by weight) |

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